High Frequency Chip Inductor (Lead Free)

HCI1005F-Series-M8

1.Features

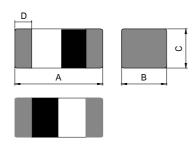
- 1. Monolithic inorganic material construction.
- 2. Closed magnetic circuit avoids crosstalk.
- 3. S.M.T. type.
- 4. Suitable for reflow soldering.
- 5. Shapes and dimensions follow E.I.A. spec.
- 6. Available in various sizes.
- 7. Excellent solder ability and heat resistance.
- 8. High SRF up to 6GHz and above.
- 9. 100% Lead(Pb) & Halogen-Free and RoHS compliant.







2. Dimensions



Chip Size						
Α	1.00±0.05					
В	0.50±0.05					
С	0.50±0.05					
D	0.25±0.10					

Units: mm

3. Part Numbering



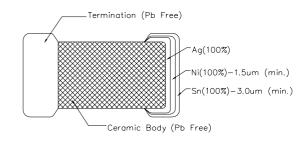
A: Series

B: Dimension L x W

C: Material Lead Free Material
D: Inductance 6N8=6.8 nH

E: Inductance Tolerance J=±5%, K=±10%

F: MARKING



4. Specification

Tai-Tech	Inductance	Test Frequency	Q	Q (Typ.) Frequency(MHz)		Rated Current DCR ()		SRF (MHz)					
Part Number	(nH)	(MHz)	min.	100	300	500	800	1000	(mA) max	max.	typ.	min.	typ.
HCI1005F-1N0S-M8	1.0	100	8	11	25	34	43	52	300	0.08	0.04	10000	>13000
HCI1005F-1N2S-M8	1.2	100	8	11	25	35	44	52	300	0.09	0.04	10000	>13000
HCI1005F-1N5S-M8	1.5	100	8	11	24	33	44	48	300	0.10	0.05	6000	>13000
HCI1005F-1N8S-M8	1.8	100	8	11	23	30	36	42	300	0.12	0.06	6000	11000
HCI1005F-2N0S-M8	2.0	100	8	11	21	27	34	39	300	0.12	0.06	6000	10500
HCI1005F-2N2S-M8	2.2	100	8	10	18	25	31	36	300	0.13	0.07	6000	10000
HCI1005F-2N4S-M8	2.4	100	8	10	18	24	31	35	300	0.13	0.07	6000	9500
HCI1005F-2N7S-M8	2.7	100	8	10	18	24	31	34	300	0.13	0.08	6000	9000
HCI1005F-3N0S-M8	3.0	100	8	10	18	24	31	35	300	0.16	0.09	6000	8500

TAI-TECH

Tai-Tech	Inductance	Test	Q	Q	(Тур.)	Freque	ency(MI	Hz)	Rated Current	DCR	2()	SRF	(MHz)
Part Number	(nH)	Frequency (MHz)	min.	100	300	500	800	1000	(mA) max	max.	typ.	min.	typ.
HCI1005F-3N3S-M8	3.3	100	8	10	18	24	31	35	300	0.16	0.10	6000	8000
HCI1005F-3N6S-M8	3.6	100	8	10	18	24	31	35	300	0.20	0.11	5000	7500
HCI1005F-3N9S-M8	3.9	100	8	10	18	24	31	35	300	0.21	0.12	4000	7000
HCI1005F-4N3S-M8	4.3	100	8	10	18	24	31	35	300	0.20	0.12	4000	6500
HCI1005F-4N7S-M8	4.7	100	8	10	18	24	31	34	300	0.21	0.12	4000	6000
HCI1005F-5N1S-M8	5.1	100	8	10	18	24	31	34	300	0.21	0.13	4000	5800
HCI1005F-5N6S-M8	5.6	100	8	10	18	24	30	35	300	0.23	0.15	4000	5700
HCI1005F-6N2S-M8	6.2	100	8	10	18	24	30	34	300	0.25	0.16	3900	5600
HCI1005F-6N8 -M8	6.8	100	8	10	18	23	29	32	300	0.25	0.17	3900	5500
HCI1005F-7N5 -M8	7.5	100	8	10	18	23	29	32	300	0.25	0.18	3700	5200
HCI1005F-8N2 -M8	8.2	100	8	10	18	23	29	31	300	0.28	0.21	3600	4900
HCI1005F-9N1 -M8	9.1	100	8	10	18	23	29	31	300	0.30	0.22	3400	4500
HCI1005F-10N -M8	10	100	8	10	18	23	29	31	300	0.31	0.23	3200	4300
HCI1005F-12N -M8	12	100	8	11	18	23	29	31	300	0.40	0.28	2700	3900
HCI1005F-15N -M8	15	100	8	11	18	23	28	30	300	0.46	0.31	2300	3500
HCI1005F-18N -M8	18	100	8	11	18	23	28	30	300	0.55	0.35	2100	3100
HCI1005F-22N -M8	22	100	8	11	17	22	26	27	300	0.60	0.42	1900	2800
HCI1005F-27N -M8	27	100	8	11	17	21	25	26	300	0.70	0.47	1600	2300
HCI1005F-33N -M8	33	100	8	11	16	20	23	22	200	0.80	0.50	1300	1900
HCI1005F-39N -M8	39	100	8	11	16	20	23	21	200	0.90	0.52	1200	1700
HCI1005F-47N -M8	47	100	8	11	16	19	21	18	200	1.00	0.58	1000	1500
HCI1005F-56N -M8	56	100	8	11	16	18	18	16	200	1.00	0.61	750	1300
HCI1005F-68N -M8	68	100	8	11	15	17	18	11	180	1.20	0.70	750	1200
HCI1005F-82N -M8	82	100	8	10	14	16	15	6	150	1.30	0.81	600	1100
HCI1005F-R10 -M8	100	100	8	10	14	14	12	-	150	1.50	0.94	600	1000
HCI1005F-R12 -M8	120	100	8	10	12	10	-	-	150	1.60	1.10	600	800
HCI1005F-R15 -M8	150	100	8	12	17	17	-	-	140	3.20	2.57	550	920
HCI1005F-R18 -M8	180	100	8	12	16	-	_	-	130	3.70	2.97	500	810
HCI1005F-R22 -M8	220	100	8	12	16	-	_	-	120	4.20	3.29	450	700
HCI1005F-R27 -M8	270	100	8	12	14	-	-	-	110	4.80	3.92	400	600

[:] J=±5% , K=±10%

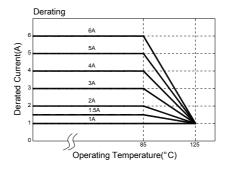
5. Reliability and Test Condition

Item					Perfor	mance					Test Condition
Series No.	FCB	FCM	НСВ	GHB	FCA	FCI	FHI	FCH	HCI	MGI	
Operating Temperature	(In		40~+125 self-temp		rise)	(In		40~+105 self-temp		rise)	-
Transportation Storage Temperature			-40~+12 <u></u>	5			-	40~+10 <u></u>	5		For long storage conditions, please see the Application Notice
Impedance (Z)		-									Agilent4291
Inductance (Ls)											Agilent E4991
Q Factor	Refe	r to stand	dard elec	trical ch	aracteris	tics list					Agilent4287 Agilent16192
DC Resistance											Agilent 4338
Rated Current											DC Power Supply Over Rated Current requirements, there will be some risk
Temperature Rise Test			A ΔT 20 1A ΔT 40								Applied the allowed DC current. Temperature measured by digital surface thermometer.
Solder heat Resistance	Imped	dance cha	lo signific ange: Witl ange: : wi	hin ± 30	%.			damage. inal elect		% min.	Preheat: 150 ,60sec. Solder: Sn-Cu0.5 Solder tamperature: 260±5 Flux for lead free: ROL0 Dip time: 10±0.5sec. Preheating Dipping Natural cooling 260°C 150°C 60 10±0.5 second
Solderability		ode sho	% of the buld be			245°C	Preheating Dip	oing Natural of	1		Preheat: 150 ,60sec. Solder: Sn-Cu0.5 Solder tamperature: 245±5 Flux for lead free: ROL0 Dip time: 4±1sec.
Terminal strength	not be		electrode ed by the s.				7117117		\	W	For FCB FCM HCB GHB
Flexture strength	not be		electrode ed by the				1	100(3.93)		Bending 40(1.575)	Solder a chip on a test substrate, bend the substrate by 2mm (0.079in)and return. The duration of the applied forces shall be 60 (+ 5) Sec.
Bending Strength			ould not			<u>R 0</u>	.5(0.02	1.0(0.039) - - - - - -			Size mm(inches) P-Kgf 1608 0.80(0.033) 0.3
Random Vibration Test	chara	acteristic dance: v	Cracking s should vithin±30 nange: : v	not be a	allowed.	ny other	defects	narmful t	to the		Frequency: 10-55-10Hz for 15 min. Amplitude: 1.52mm Directions and times: X, Y, Z directions for 15 min This cycle shall be performed 12 times in each of three mutually perpendicular directions (Total 9hours).

Item	Performance		Test Condition	
Life testing at High Temperature	Appearance: no damage. Impedance: within±30%of initial value.		Temperature: 125±2 (bead), 85±2 (inductor) Applied current: rated current. Duration: 1000±12hrs. Measured at room temperature after placing for 2 to 3hrs.	
Humidity	Inductance: within±10%of initial value. Q: within±30%of initial value. (FCI FHI FCH) Q: within±20%of initial value. (HCI MGI)	Humidity: 90~95%RH. Temperature: 40±2 . Temperature: 60±2 .(HCI MGI) Duration: 504±8hrs. Measured at room temperature after placing for 2 to 3hrs.		
Thermal shock	Impedance: within±30%of initial value. Inductance: within±10%of initial value. 2 ro	perature() Time(min.) 40±2 30±5 om temp. 0.5 105±2 30±5 Utimes	Condition for 1 cycle Step1: -40±2 30±5 min. Step2: +105±2 30±5min. Number of cycles: 500 Measured at room temperature after placing for 2 to 3 hrs.	
Low temperature storage test	Q: within±20%of initial value. (HCI MGI)		Temperature: -40±2 . Duration: 500±8hrs. Measured at room temperature after placing for 2 to 3hrs.	
Drop	No mechanical damage Impedance change: ±30% Inductance change: : within±10%		Drop 10 times on a concrete floor from a height of 75cm	

**Derating Curve

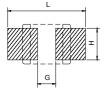
For the ferrite chip bead which withstanding current over 1.5A, as the operating temperature over 85 , the derating current information is necessary to consider with. For the detail derating of current, please refer to the Derated Current vs. Operating Temperature curve.



6. Soldering and Mounting

6-1. Recommended PC Board Pattern

Chip Size							d Patterns low Solde	
Series	Туре	A(mm)	B(mm)	C(mm)	D(mm)	L(mm)	G(mm)	H(mm)
	0603	0.6±0.03	0.30±0.03	0.30±0.03	0.15±0.05	0.80	0.20~0.30	0.25~0.40
HCI	1005	1.0±0.05	0.50±0.05	0.50±0.05	0.25±0.10	1.50	0.45~0.55	0.45~0.55



PC board should be designed so that products can prevent damage from mechanical stress when warping the board.

Products shall be positioned in the sideway direction against the mechanical stress to prevent failure.

6-2. Soldering

Mildly activated rosin fluxes are preferred. The terminations are suitable for re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

Note.

If wave soldering is used ,there will be some risk.

Re-flow soldering temperatures below 240 degrees, there will be non-wetting risk

6-2.1 Lead Free Solder re-flow:

Recommended temperature profiles for lead free re-flow soldering in Figure 1.

6-2.2 Soldering Iron:

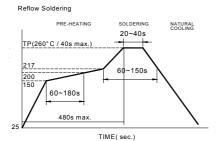
Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended. for Iron Soldering in Figure 2.

Preheat circuit and products to 150 350 tip temperature (max)

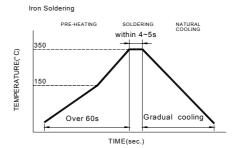
Never contact the ceramic with the iron tip

Use a 20 watt soldering iron with tip diameter of 1.0mm Limit soldering time to 4~5sec.

rature (max) 1.0mm tip diameter (max)



Reflow times: 3 times max Fig.1

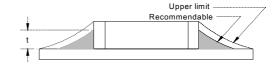


Iron Soldering times: 1 times max Fig.2

6-2.3 Solder Volume:

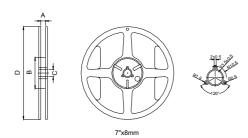
Accordingly increasing the solder volume, the mechanical stress to product is also increased. Exceeding solder volume may cause the failure of mechanical or electrical performance. Solder shall be used not to be exceed as shown in right side:

Minimum fillet height = soldering thickness + 25% product height



7. Packaging Information

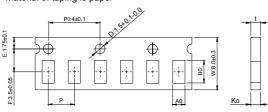
7-1. Reel Dimension



Туре	A(mm)	B(mm)	C(mm)	D(mm)
7"x8mm	9.0±0.5	60±2	13.5±0.5	178±2

7-2 Tape Dimension / 8mm

Material of taping is paper



2.1	P2:2±0.1 P0:4±0.1 D1:60*A1.10.05	- t -
E:1.75±0.1		
F. 3	P A0	Ko

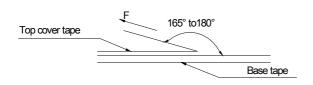
Size	Bo(mm)	Ao(mm)	Ko(mm)	P(mm)	t(mm)
060303	0.70±0.06	0.40±0.06	0.45max	2.0±0.05	0.45max

Size	Bo(mm)	Ao(mm)	Ko(mm)	P(mm)	t(mm)
 100505	1.15±0.10	0.65±0.10	0.80max	2.0±0.05	0.80max

7-3. Packaging Quantity

Chip Size	100505	060303
Chip / Reel	10000	15000
Inner box	50000	75000
Middle box	250000	375000
Carton	500000	750000

7-4. Tearing Off Force



The force for tearing off cover tape is 15 to 60 grams in the arrow direction under the following conditions.

Room Temp.	Room Temp. Room Humidity		Tearing Speed	
()	(%)	(hPa)	mm/min	
5~35	45~85	860~1060	300	

Application Notice

Storage Conditions

To maintain the solder ability of terminal electrodes:

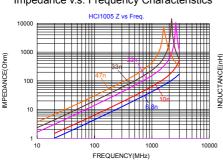
- 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
- 2. Temperature and humidity conditions: -10~ 40 and 30~70% RH.
- 3. Recommended products should be used within 6 months from the time of delivery.
- 4. The packaging material should be kept where no chlorine or sulfur exists in the air.

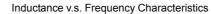
Transportation

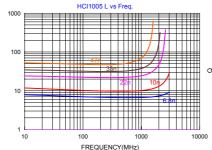
- 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- 2. The use of tweezers or vacuum pick up is strongly recommended for individual components.
- 3. Bulk handling should ensure that abrasion and mechanical shock are minimized.

Impedance, Inductance, Q v.s Frequency Characteristics(Typical)

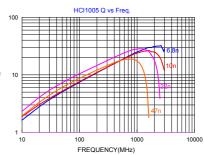








Q v.s. Frequency Characteristics



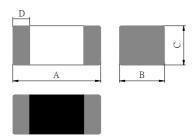
High Frequency Chip Inductor (Lead Free)

HCI1608F-Series-M

1. Features

- 1. Monolithic inorganic material construction.
- 2. Closed magnetic circuit avoids crosstalk.
- 3. S.M.T. type.
- 4. Suitable for reflow soldering.
- 5. Shapes and dimensions follow E.I.A. spec.
- 6. Available in various sizes.
- 7. Excellent solder ability and heat resistance.
- 8. High SRF up to 6GHz and above.
- 9. 100% Lead(Pb) & Halogen-Free and RoHS compliant.

2. Dimensions



Chip Size							
Α	1.60±0.15						
В	0.80±0.15						
С	0.80±0.15						
D	0.30±0.20						

Units: mm

3. Part Numbering



A: Series

B: Dimension L x W

C: Material Lead Free Material
D: Inductance 1N5=1.5 nH

E: Inductance Tolerance S=±0.3nH , J=±5% , K=±10%

F: MARKING

4. Specification

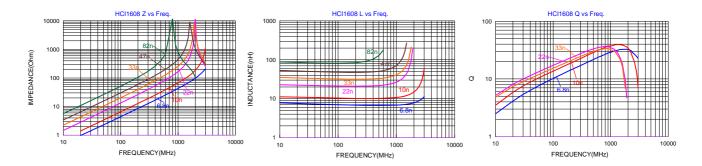
Tai-Tech	Thickness	Inductance		Q		Rated Current	DCR	SRF
Part Number	(mm)	(nH)	Test Frequency (MHz)	Normal Value	min.	(mA) max.	(Ω) max.	(MHz) min.
HCI1608F-1N0S-M	0.80±0.15	1.0	100	14	8	300	0.05	10000
HCI1608F-1N2S-M	0.80±0.15	1.2	100	14	8	300	0.05	10000
HCI1608F-1N5S-M	0.80±0.15	1.5	100	14	8	300	0.10	6000
HCI1608F-1N8S-M	0.80±0.15	1.8	100	10	8	300	0.10	6000
HCI1608F-2N2S-M	0.80±0.15	2.2	100	12	8	300	0.10	6000
HCI1608F-2N7S-M	0.80±0.15	2.7	100	13	10	300	0.10	6000
HCI1608F-3N3S-M	0.80±0.15	3.3	100	14	10	300	0.12	6000
HCI1608F-3N9S-M	0.80±0.15	3.9	100	13	10	300	0.14	6000

TAI-TECH

Tai-Tech	Thickness	Inductance		Q		Rated Current	DCR	SRF
Part Number	(mm)	(nH)	Test Frequency (MHz)	Normal Value	min.	(mA) max.	(Ω) max.	(MHz) min.
HCI1608F-4N7S-M	0.80±0.15	4.7	100	13	10	300	0.16	4000
HCI1608F-5N6S-M	0.80±0.15	5.6	100	14	10	300	0.18	4000
HCI1608F-6N8 -M	0.80±0.15	6.8	100	14	10	300	0.22	4000
HCI1608F-8N2M	0.80±0.15	8.2	100	14	10	300	0.24	3500
HCI1608F-10N□-M	0.80±0.15	10	100	14	12	300	0.26	3400
HCI1608F-12N□-M	0.80±0.15	12	100	14	12	300	0.28	2600
HCI1608F-15N□-M	0.80±0.15	15	100	15	12	300	0.32	2300
HCI1608F-18N□-M	0.80±0.15	18	100	15	12	300	0.35	2000
HCI1608F-22N□-M	0.80±0.15	22	100	16	12	300	0.40	1600
HCI1608F-27N□-M	0.80±0.15	27	100	16	12	300	0.45	1400
HCI1608F-33N□-M	0.80±0.15	33	100	17	12	300	0.55	1200
HCI1608F-39N□-M	0.80±0.15	39	100	18	12	300	0.60	1100
HCI1608F-47N□-M	0.80±0.15	47	100	17	12	300	0.70	900
HCI1608F-56N□-M	0.80±0.15	56	100	17	12	300	0.75	900
HCI1608F-68N□-M	0.80±0.15	68	100	18	12	300	0.85	700
HCI1608F-82N□-M	0.80±0.15	82	100	18	12	300	0.95	600
HCI1608F-R10 -M	0.80±0.15	100	100	18	12	300	1.00	600
HCI1608F-R12 -M	0.80±0.15	120	50	16	8	300	1.20	500
HCI1608F-R15M	0.80±0.15	150	50	13	8	300	1.20	500
HCI1608F-R18M	0.80±0.15	180	50	13	8	300	1.30	400

NOTE: :TOLERANCE J:+/-5% K:+/-10%

Impedance, Inductance, Q v.s. Frequency Characteristics(Typical)





Test Report

號碼(No.): CE/2012/24508 日期(Date): 2012/02/29 頁數(Page): 1 of 7

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

100

(東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.)

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

(廣東省東莞市黃江鎮黃牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN; DONGGUAN, GUANGDONG) (江蘇省昆山市蓬朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU,

以下測試樣品係由客户送樣, 且由客户聲稱並經客户確認如下 (The following samples was/were submitted and identified by/on behalf of the client as):

樣品名稱(Sample Description)

HCI, MGI, UHI, THI, HCI-M, THI-M, TCI SERIES

樣品型號(Style/Item No.)

HCI, MGI, UHI, THI, HCI-M, THI-M, TCI SERIES

收件日期(Sample Receiving Date)

2012/02/21

測試期間(Testing Period)

2012/02/21 TO 2012/02/29

測試結果(Test Results)

: 請見下一頁 (Please refer to next pages).

Chenyu Kung / Signed for and on hehalf SGS TAIWAN LTD. Chemical Laboratory - Taipei

Unless otherwise stated the results shown in this test report refer only to the sample(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the Company 除非另有認明,此報告結果條劃測式之樣具負責。本報告来經本公司書面許可,不可部分模型。
This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_end_conditions.htm and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/en/Terms-end-Conditions/Terms-e-Document. Attention is drawn to the imitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of Client's instructions, if any. The Company's of responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced except in full, without prior written permission of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law.



Test Report

號碼(No.): CE/2012/24508 日期(Date): 2012/02/29 頁數(Page): 2 of 7

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.)

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOU'TH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

(廣東省東莞市黄江鎮黄牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN, DONGGUAN, GUANGDONG) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

测試結果(Test Results)

測試部位(PART NAME) No.1:

整體混測 (3款) (MIXED ALL PARTS (3 KINDS))

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鎬 / Cadmium (Cd)	mg/kg	參考IEC 62321: 2008方法, 以感 應耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321: 2008 and performed by ICP-AES.		n.d.
発 / Lead (Pb)	mg/kg	參考IEC 62321: 2008方法, 以感 應耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321: 2008 and performed by ICP-AES.	2	n.d.
汞 / Mercury (Hg)	mg/kg	參考IEC 62321: 2008方法, 以感 應耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321: 2008 and performed by ICP-AES.	2	n.d.
六價絡 / Hexavalent Chromium Cr(VI)	mg/kg	多考IEC 62321: 2008方法,以UV-VIS檢測. / With reference to IEC 62321: 2008 and performed by UV-VIS.	2	n.d.
鹵素 / Halogen	ŀ			
鹵素 (氣) / Halogen-Fluorine (F) (CAS No.: 14762-94-8)			50	n.d.
鹵素 (氣) / Halogen-Chlorine (Cl) (CAS No.: 22537-15-1)		参考BS EN 14582:2007, 以離子層 析儀分析. / With reference to	50	n.d.
鹵素 (溴) / Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	BS EN 14582:2007. Analysis was performed by IC.	50	n.d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)			50	n.d.

Unless otherwise stated the results shown in this test report refer only to the sample(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the Company 除非另有說明,此報告結果僅到測試之樣是負責。本報告未經本公司書面許可,不可部分發展。
This document is Issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_end_conditions.htm and, for elsectronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/en/Terms-end-Conditions/Terms-e-Document. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of Client's instructions, if any. The Company's sole responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced except in full, without prior written approval of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law.



Test Report

號碼(No.): CE/2012/24508 日期(Date): 2012/02/29 頁數(Page): 3 of 7

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.)

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

(廣東省東莞市黃江鎮黃牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN, DONGGUAN, GUANGDONG) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法負測 極限値 (MDL)	結果 (Result) No.1
多溴聯苯總和 / Sum of PBBs			_	n.d.
一溴聯苯 / Monobromobiphenyl			5	n.d.
二溴聯苯 / Dibromobiphenyl			5	n.d.
三溴聯苯 / Tribromobiphenyl			5	n.d.
四溴聯苯 / Tetrabromobiphenyl			5	n.d.
五溴聯苯 / Pentabromobiphenyl			5	n.d.
六溴聯苯 / Hexabromobiphenyl			5	n.d.
七溴聯苯 / Heptabromobiphenyl		参考IEC 62321: 2008方法,以氣	5	n.d.
八溴聯苯 / Octabromobiphenyl			5	n.d.
九溴聯苯 / Nonabromobiphenyl			5	n.d.
十溴聯苯 / Decabromobiphenyl	mg/kg	相層析儀/質譜儀檢測. / With	5	n.d.
多溴聯苯醚總和 / Sum of PBDEs 一溴聯苯醚 / Monobromodiphenyl ether		reference to IEC 62321: 2008 and performed by GC/MS.	_	n.d.
			5	n.d.
二溴聯苯醚 / Dibromodiphenyl ether			5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether			5	n.d.
四溴聯苯醚 / Tetrabromodiphenyl ether	-		5	n.d.
五溴聯苯醚 / Pentabromodiphenyl ether			5	n.d.
六溴聯苯醚 / Hexabromodiphenyl ether			5	n.d.
七溴聯苯醚 / Heptabromodiphenyl ether			5	n.d.
八溴聯苯醚 / Octabromodiphenyl ether			5 .	n.d.
九溴聯苯醚 / Nonabromodiphenyl ether		·	5	n.d.
十溴聯苯醚 / Decabromodiphenyl ether			5	n.d.

備註(Note):

- 1. mg/kg = ppm; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個别單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

Unless otherwise stated the results shown in this test report refer only to the sample(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the Company 除非另有認明,此報告結果報言例述之樣品負貨。本報告来經本公司書面許可,不可部分模製。
This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_end_conditions.htm and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/terms_end-Conditions/Terms-e-Document, Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of Client's instructions, if any. The Company's sole responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced except in full, without prior written approval of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law.



Test Report

號碼(No.) : CE/2012/24508 - 日期(Date) : 2012/02/29 - 頁數(Page) : 4 of 7

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

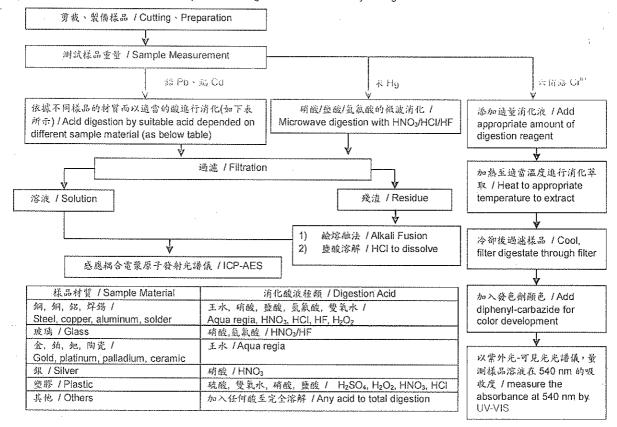
(東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.)

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

(廣東省東莞市黄江鎮黄牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN, DONGGUAN, GUANGDONG) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU,

- 1) 根據以下的流程關之條件,樣品已完全溶解。(六價絡測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr6+ test method excluded)
- 测試人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 测试负责人: 張啓興 / Name of the person in charge of measurement: Troy Chang



Unless otherwise stated the results shown in this test report refer only to the sample(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the Company.除进另有認明,此報告結果能影測就之樣最复音。本報告未經本公司評価許可,不可部分模型。
This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_end_Conditions.htm and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/en/Terms-end-Conditions/Terms-e-Document. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's sindings at the time of its intervention only and within the limits of Client's instructions, if any. The Company's sole responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced except in full, without prior written permission of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law.



號碼(No.): CE/2012/24508 日期(Date): 2012/02/29 頁數(Page): 5 of 7

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.)

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

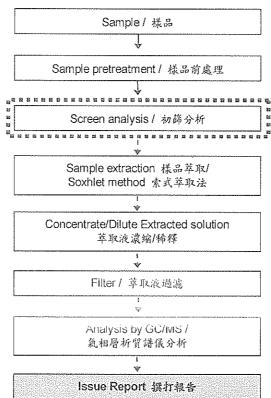
(廣東省東莞市黃江鎮黃牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN, DONGGUAN, GUANGDONG) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

- 测試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong
- 渊試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang

選擇性篩檢程序 / Optional screen process

確認程序 / Confirmation process - · - - *



Unless otherwise stated the results shown in this test report refer only to the sample(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the Company 緊非另有認明,此間告結果循到測試之樣品負貨。本術告来經本公司書面許可,不可部分複製。
This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_and_conditions.htm and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/en/Terms-and-Conditions/Terms-e-Document. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's sindings at the of its intervention only and within the limits of Client's instructions, if any. The Company's sole responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced except in full, without prior written permission of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law.



測試報告 Test Report

號碼(No.): CE/2012/24508 日期(Date): 2012/02/29 頁數(Page): 6 of 7

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

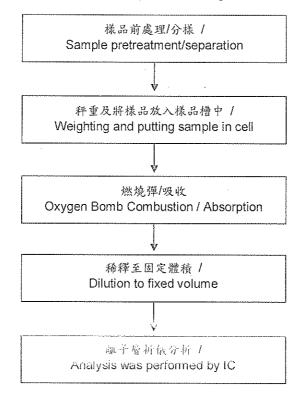
(東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.) (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

(廣東省東莞市黄江鎮黄牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN, DONGGUAN, GUANGDONG) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA)

鹵素分析流程圖 / Analytical flow chart of halogen content

- 測試入員:陳思臻 / Name of the person who made measurement: Rita Chen
- 测試負責人:張啓典 / Name of the person in charge of measurement: Troy Chang



Unless otherwise stated the results shown in this test report refer only to the sample(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the Company 除非另有認明,此間告緒果頓到排記之程品負責。本報告来經本公司書面許可,不可部分複製。
This document is issued by the Company subject to to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_and_conditions.htm and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/en/Terms-and-Conditions/Terms-e-Document. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of Client's instructions, if any. The Company's sole responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced except in full, without prior written permission of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law.



Test Report

日期(Date): 2012/02/29 頁数(Page): 7 of 7 號碼(No.): CE/2012/24508

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(東莞臺慶精密電子有限公司 / TAI-TECH ADVANCED ELECTRONICS (DONGGUAN) CO., LTD.)

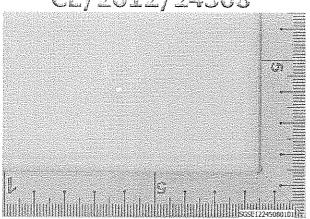
(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.) 桃園縣楊梅市幼獅工業區幼四路1之1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI CITY, TAO-YUAN HSIEN, TAIWAN, R. O. C.)

(廣東省東莞市黄江鎮黄牛埔福祥街2號 / NO. 2, FUXIANG STREET, HUANGNIUPU, HUANGJIANG TOWN, DONGGUAN, GUANGDONG) (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) -

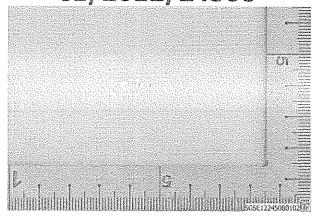
* 照片中如有箭頭標示,則表示爲實際檢測之樣品/部位. *

(The tested sample / part is marked by an arrow if it's shown on the photo.)

CE/2012/24508



CE/2012/24508



** 報告結尾(End of Report) **

e(s) tested. This test report cannot be reproduced, except in full, without prior written permission of the 評句,不可部分複變。 · 此報告結果僅對關訊之樣品負責。本報告未絕本公司書籍許可,不可需分複製。 by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at www.sgs.com/terms_and_conditions.htm

and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at www.sgs.com/en/Terms-and-Conditions/T